National Semiconductor

CD4073BM/CD4073BC Double Buffered Triple 3-Input AND Gate
CD4075BM/CD4075BC Double Buffered Triple 3-Input OR Gate

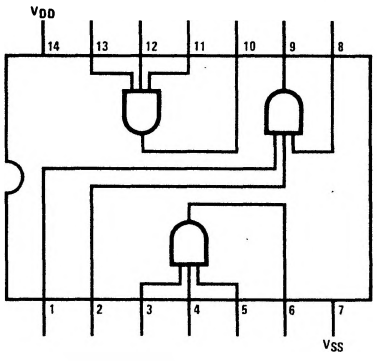
General Description

These triple gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain. All inputs are protected against static discharge with diodes to V_{DD} and V_{SS}.

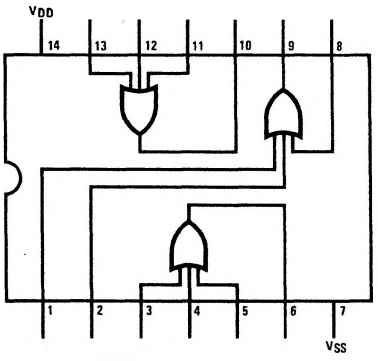
Features

- Wide supply voltage range — 3.0V to 15V
- High noise immunity — 0.45 V_{DD} typ.
- Low power TTL compatibility — fan out of 2 driving 74L or 1 driving 74LS
- 5V - 10V - 15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 μA at 15V over full temperature range

Connection Diagrams



CD4073 Triple 3-Input AND Gate
TOP VIEW



CD4075B Triple 3-Input OR Gate
TOP VIEW

Absolute Maximum Ratings (Notes 1 and 2)

V_{DD}	DC Supply Voltage	$-0.5\ V_{DC}$ to $+18\ V_{DC}$
V_{IN}	Input Voltage	$-0.5\ V_{DC}$ to $V_{DD} + 0.5\ V_{DC}$
T_S	Storage Temperature Range	$-65°C$ to $+150°C$
P_D	Package Dissipation	500 mW
T_L	Lead Temperature (soldering, 10 seconds)	300°C

Operating Conditions (Note 2)

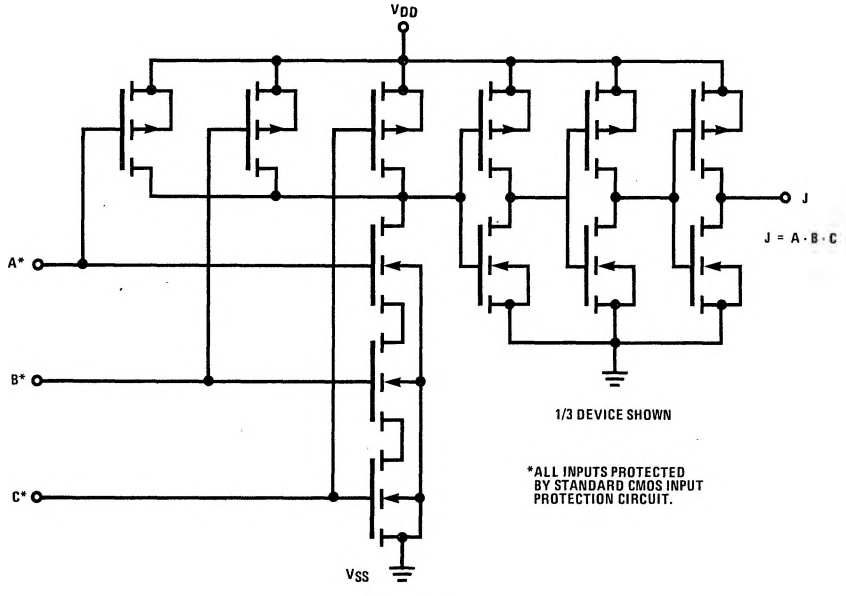
V_{DD}	DC Supply Voltage	$+5\ V_{DC}$ to $+15\ V_{DC}$
V_{IN}	Input Voltage	$0\ V_{DC}$ to $V_{DD}\ V_{DC}$
T_A	Operating Temperature Range	
CD4073BM/CD4075BM		$-55°C$ to $+125°C$
CD4073BC/CD4075BC		$-40°C$ to $+85°C$

DC Electrical Characteristics CD4073BM/CD4075BM (Note 2)

PARAMETER		CONDITIONS	−55°C		+25°C			+125°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	$V_{DD} = 5\ V$		0.25		0.004	0.25		7.5	μA
		$V_{DD} = 10\ V$		0.5		0.005	0.5		15	μA
		$V_{DD} = 15\ V$		1.0		0.006	1.0		30	μA
V_{OL}	Low Level Output Voltage	$V_{DD} = 5\ V$ | $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
		$V_{DD} = 10\ V$ | $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
		$V_{DD} = 15\ V$ | $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$V_{DD} = 5\ V$ | $\lvert I_O \rvert < 1\ \mu A$	4.95		4.95	5		4.95		V
		$V_{DD} = 10\ V$ | $\lvert I_O \rvert < 1\ \mu A$	9.95		9.95	10		9.95		V
		$V_{DD} = 15\ V$ | $\lvert I_O \rvert < 1\ \mu A$	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	$V_{DD} = 5\ V,\ V_O = 0.5\ V$ | $\lvert I_O \rvert < 1\ \mu A$		1.5		2	1.5		1.5	V
		$V_{DD} = 10\ V,\ V_O = 1.0\ V$ | $\lvert I_O \rvert < 1\ \mu A$		3.0		4	3.0		3.0	V
		$V_{DD} = 15\ V,\ V_O = 1.5\ V$ | $\lvert I_O \rvert < 1\ \mu A$		4.0		6	4.0		4.0	V
V_{IH}	High Level Input Voltage	$V_{DD} = 5\ V,\ V_O = 4.5\ V$ | $\lvert I_O \rvert < 1\ \mu A$	3.5		3.5	3		3.5		V
		$V_{DD} = 10\ V,\ V_O = 9.0\ V$ | $\lvert I_O \rvert < 1\ \mu A$	7.0		7.0	6		7.0		V
		$V_{DD} = 15\ V,\ V_O = 13.5\ V$ | $\lvert I_O \rvert < 1\ \mu A$	11.0		11.0	9		11.0		V
I_{OL}	Low Level Output Current	$V_{DD} = 5\ V,\ V_O = 0.4\ V$	0.64		0.51	0.88		0.36		mA
		$V_{DD} = 10\ V,\ V_O = 0.5\ V$	1.6		1.3	2.2		0.90		mA
		$V_{DD} = 15\ V,\ V_O = 1.5\ V$	4.2		3.4	8		2.4		mA
I_{OH}	High Level Output Current	$V_{DD} = 5\ V,\ V_O = 4.6\ V$	−0.64		−0.51	−0.88		−0.36		mA
		$V_{DD} = 10\ V,\ V_O = 9.5\ V$	−1.6		−1.3	−2.2		−0.90		mA
		$V_{DD} = 15\ V,\ V_O = 13.5\ V$	−4.2		−3.4	−8		−2.4		mA
I_{IN}	Input Current	$V_{DD} = 15\ V,\ V_{IN} = 0\ V$		−0.10		-10^{-5}	−0.10		−1.0	μA
		$V_{DD} = 15\ V,\ V_{IN} = 15\ V$		0.10		10^{-5}	0.10		1.0	μA

Notes on following page.

Schematic Diagram



CD4073BC

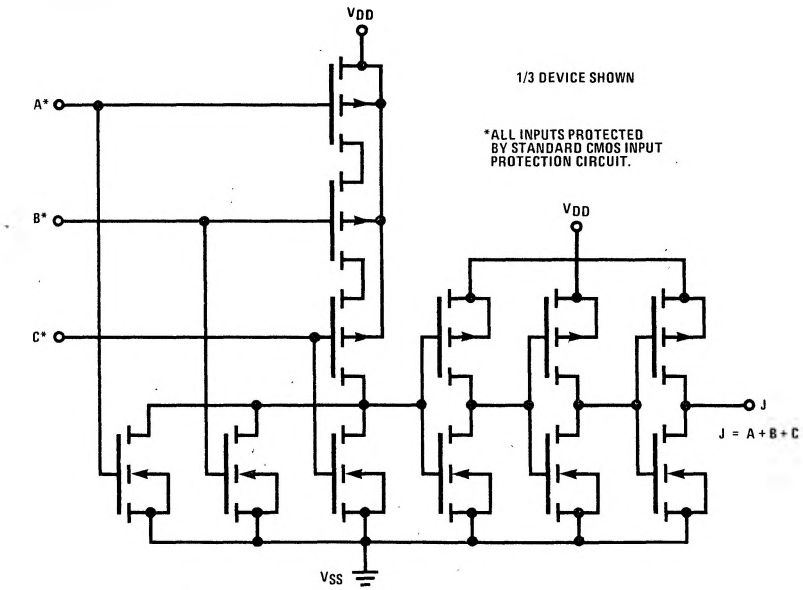
DC Electrical Characteristics CD4073BC/CD4075BC (Note 2)

PARAMETER		CONDITIONS	-40°C		+25°C			+85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5 V		1		0.004	1		7.5	μA
		V_{DD} = 10 V		2		0.005	2		15	μA
		V_{DD} = 15 V		4		0.006	4		30	μA
V_{OL}	Low Level Output Voltage	V_{DD} = 5 V, $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
		V_{DD} = 10 V, $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
		V_{DD} = 15 V, $\lvert I_O \rvert < 1\ \mu A$		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	V_{DD} = 5 V, $\lvert I_O \rvert < 1\ \mu A$	4.95		4.95	5		4.95		V
		V_{DD} = 10 V, $\lvert I_O \rvert < 1\ \mu A$	9.95		9.95	10		9.95		V
		V_{DD} = 15 V, $\lvert I_O \rvert < 1\ \mu A$	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	V_{DD} = 5 V, V_O = 0.5 V, $\lvert I_O \rvert < 1\ \mu A$		1.5		2	1.5		1.5	V
		V_{DD} = 10 V, V_O = 1.0 V, $\lvert I_O \rvert < 1\ \mu A$		3.0		4	3.0		3.0	V
		V_{DD} = 15 V, V_O = 1.5 V, $\lvert I_O \rvert < 1\ \mu A$		4.0		6	4.0		4.0	V
V_{IH}	High Level Input Voltage	V_{DD} = 5 V, V_O = 4.5 V, $\lvert I_O \rvert < 1\ \mu A$	3.5		3.5	3		3.5		V
		V_{DD} = 10 V, V_O = 9.0 V, $\lvert I_O \rvert < 1\ \mu A$	7.0		7.0	6		7.0		V
		V_{DD} = 15 V, V_O = 13.5 V, $\lvert I_O \rvert < 1\ \mu A$	11.0		11.0	9		11.0		V
I_{OL}	Low Level Output Current	V_{DD} = 5 V, V_O = 0.4 V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10 V, V_O = 0.5 V	1.3		1.1	2.2		0.90		mA
		V_{DD} = 15 V, V_O = 1.5 V	3.6		3.0	8		2.4		mA
I_{OH}	High Level Output Current	V_{DD} = 5 V, V_O = 4.6 V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10 V, V_O = 9.5 V	−1.3		−1.1	−2.2		−0.90		mA
		V_{DD} = 15 V, V_O = 13.5 V	−3.6		−3.0	−8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15 V, V_{IN} = 0 V		−0.30		-10^{-5}	−0.30		−1.0	μA
		V_{DD} = 15 V, V_{IN} = 15 V		0.30		10^{-5}	0.30		1.0	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0 V unless otherwise specified.

Schematic Diagram



CD4075BC

AC Electrical Characteristics

CD4073BM/CD4073BC/CD4075BM/CD4075BC
$T_A = 25°C$, $C_L = 50\,pF$, $R_L = 200\,k$ unless otherwise specified.

PARAMETER		CONDITIONS	CD4073BC CD4073BM			CD4075BC CD4075BM			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
t_{PHL}	Propagation Delay, High to Low Level	$V_{DD} = 5\,V$		130	250		140	250	ns
		$V_{DD} = 10\,V$		60	100		70	100	ns
		$V_{DD} = 15\,V$		40	70		50	70	ns
t_{PLH}	Propagation Delay, Low to High Level	$V_{DD} = 5\,V$		140	250		130	250	ns
		$V_{DD} = 10\,V$		70	100		50	100	ns
		$V_{DD} = 15\,V$		50	70		40	70	ns
t_{THL}	Transition Time	$V_{DD} = 5\,V$		90	200		90	200	ns
t_{TLH}		$V_{DD} = 10\,V$		50	100		50	100	ns
		$V_{DD} = 15\,V$		40	80		40	80	ns
C_{IN}	Average Input Capacitance (See Note 3)	Any Input		5	7.5		5	7.5	pF
C_{PD}	Power Dissipation Capacity (See Note 4)	Any Gate		17			17		pF

Note 3: Capacitance is guaranteed by periodic testing.

Note 4: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family characteristics Application Note AN-90.